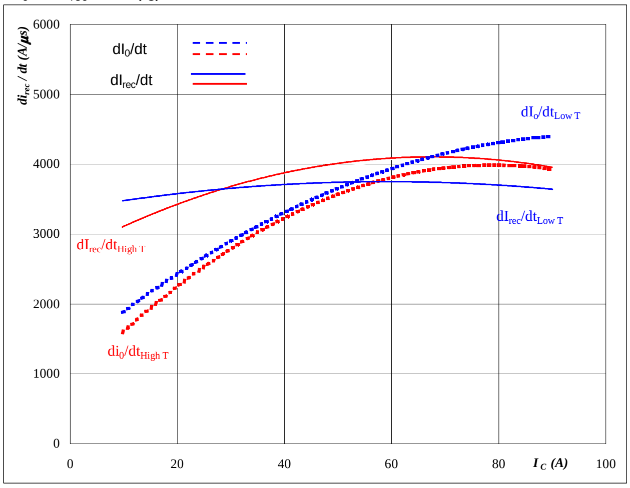
T1,T2,T3,T4,T5,T6/D1,D2,D3,D4,D5,D6

Figure 17 D1,D2,D3,D4,D5,D6 FWD

Typical rate of fall of forward and reverse recovery current as a function of collector current

$dI_0/dt, dI_{rec}/dt = f(I_C)$



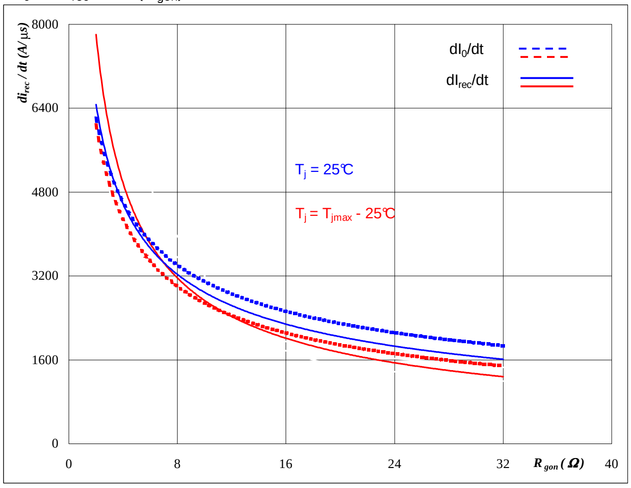
At

T_j =	25/125	℃
V_{CE} =	300	V
V_{GE} =	±15	V
R_{gon} =	8	Ω

Figure 18 D1,D2,D3,D4,D5,D6 FWD

Typical rate of fall of forward and reverse recovery current as a function of IGBT turn on gate resistor

$dI_0/dt, dI_{rec}/dt = f(R_{gon})$



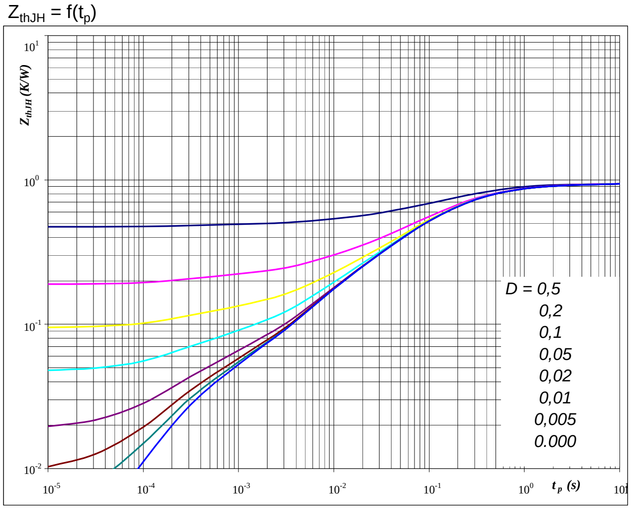
At

T_j =	25/125	℃
V_R =	300	V
I_F =	50	A
V_{GE} =	±15	V

Figure 19 T1,T2,T3,T4,T5,T6 IGBT

IGBT transient thermal impedance as a function of pulse width

$Z_{thJH} = f(t_p)$



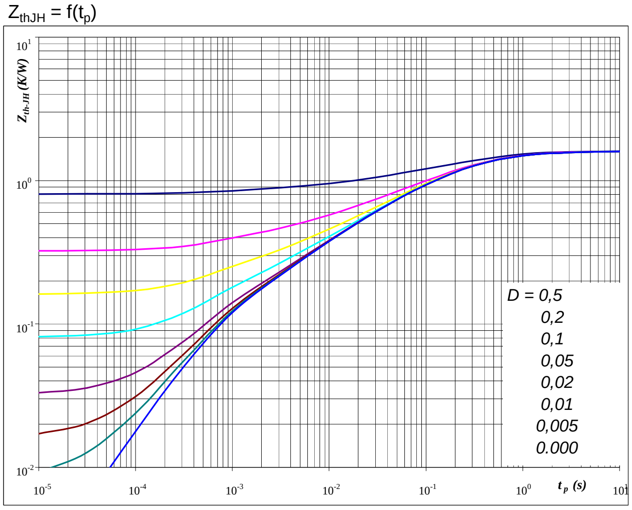
At

D =	t_p / T	
R_{thJH} =	0,95	K/W

Figure 20 D1,D2,D3,D4,D5,D6 FWD

FWD transient thermal impedance as a function of pulse width

$Z_{thJH} = f(t_p)$



At

D =	t_p / T	
R_{thJH} =	1,61	K/W

IGBT thermal model values

Thermal grease

R (C/W)	Tau (s)
0,02	9,1E+00
0,13	1,2E+00
0,45	2,0E-01
0,23	3,8E-02
0,08	5,7E-03
0,03	3,2E-04

FWD thermal model values

Thermal grease

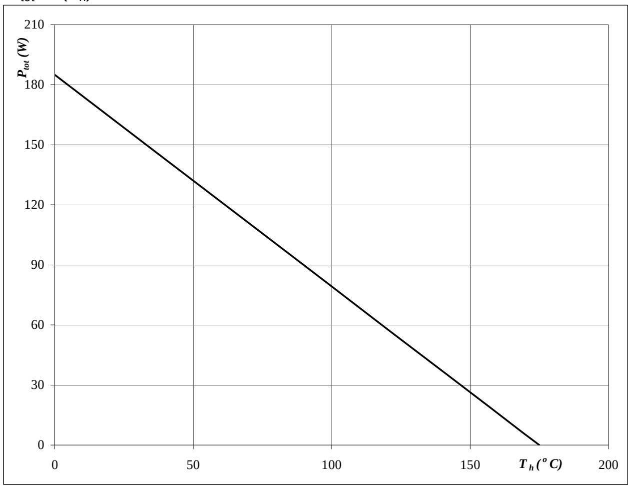
R (C/W)	Tau (s)
0,04	9,2E+00
0,22	1,0E+00
0,66	2,1E-01
0,38	4,0E-02
0,19	7,0E-03
0,11	7,5E-04

T1,T2,T3,T4,T5,T6/D1,D2,D3,D4,D5,D6

Figure 21 T1,T2,T3,T4,T5,T6 IGBT

Power dissipation as a function of heatsink temperature

$P_{tot} = f(T_h)$



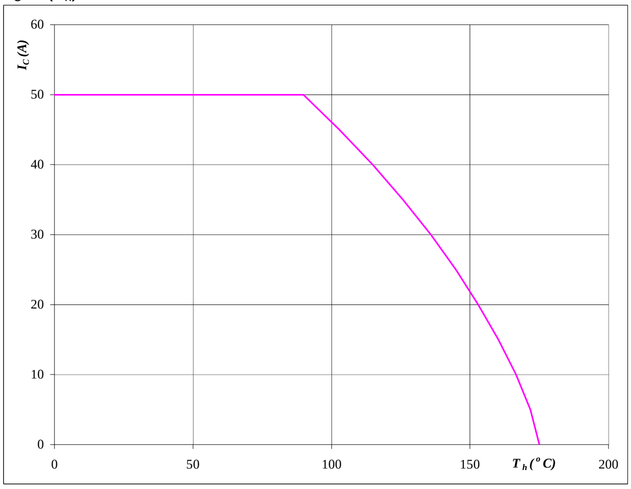
At

T_j = 175 ℃

Figure 22 T1,T2,T3,T4,T5,T6 IGBT

Collector current as a function of heatsink temperature

$I_C = f(T_h)$



At

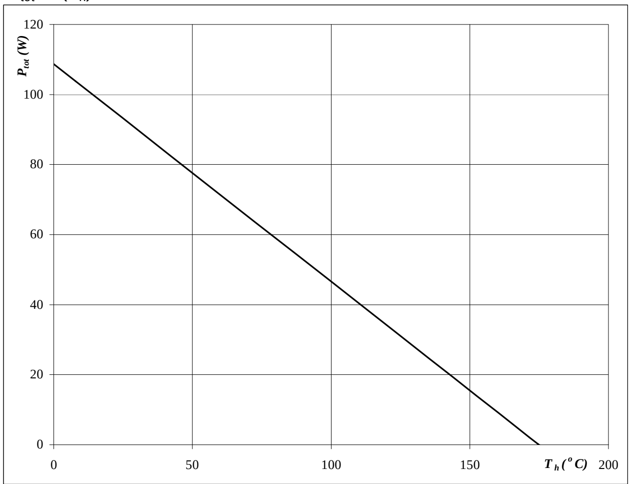
T_j = 175 ℃

V_{GE} = 15 V

Figure 23 D1,D2,D3,D4,D5,D6 FWD

Power dissipation as a function of heatsink temperature

$P_{tot} = f(T_h)$



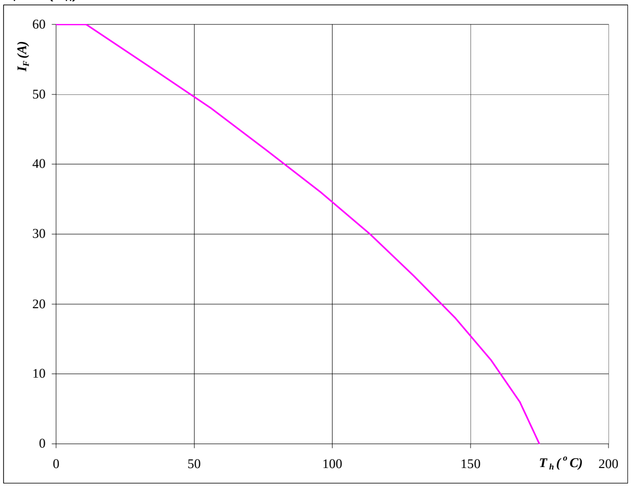
At

T_j = 175 ℃

Figure 24 D1,D2,D3,D4,D5,D6 FWD

Forward current as a function of heatsink temperature

$I_F = f(T_h)$



At

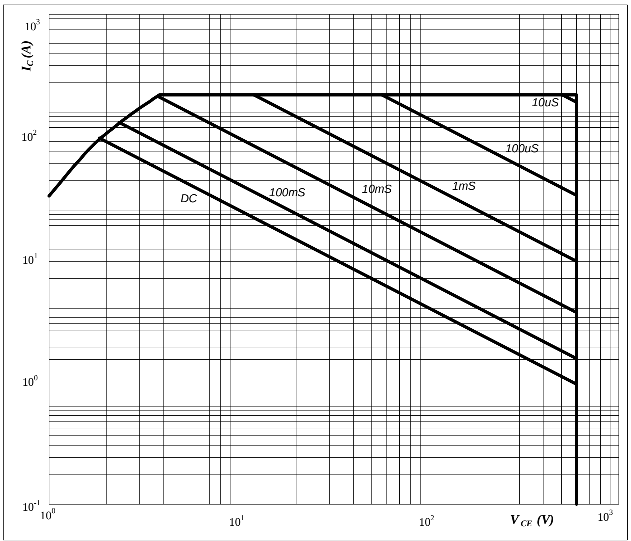
T_j = 175 ℃

T1,T2,T3,T4,T5,T6/D1,D2,D3,D4,D5,D6

Figure 25 T1,T2,T3,T4,T5,T6 IGBT

Safe operating area as a function of collector-emitter voltage

$I_C = f(V_{CE})$



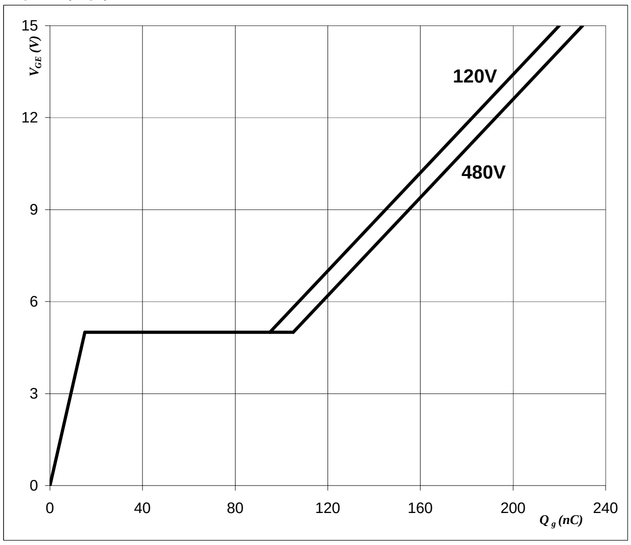
At

D =	single pulse	
T_h =	80	ºC
V_{GE} =	±15	V
T_j =	T_{jmax}	ºC

Figure 26 T1,T2,T3,T4,T5,T6 IGBT

Gate voltage vs Gate charge

$V_{GE} = f(Q_{GE})$



At

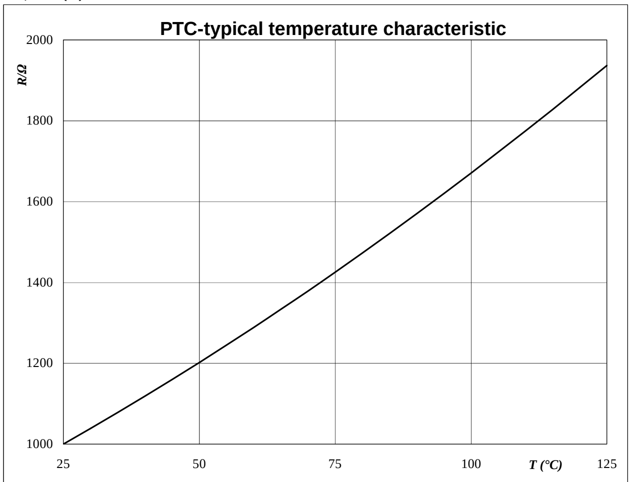
I_C =	50	A

Thermistor

Figure 1 Thermistor

Typical PTC characteristic as a function of temperature

$R_T = f(T)$



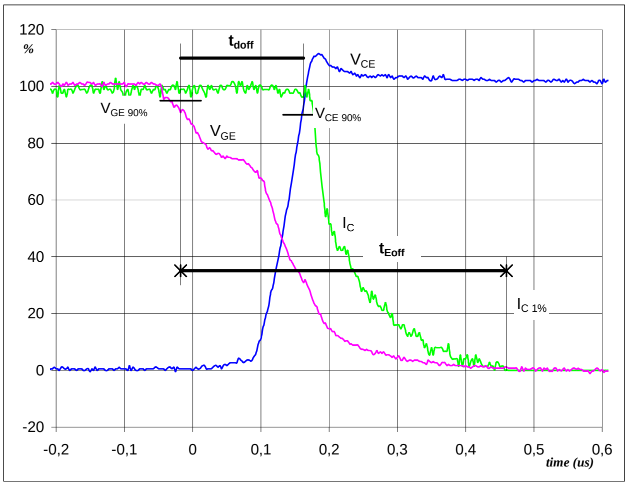
Switching Definitions Output Inverter

General conditions

T_j	=	125 °C
R_{gon}	=	8 Ω
R_{goff}	=	8 Ω

Figure 1 Output inverter IGBT

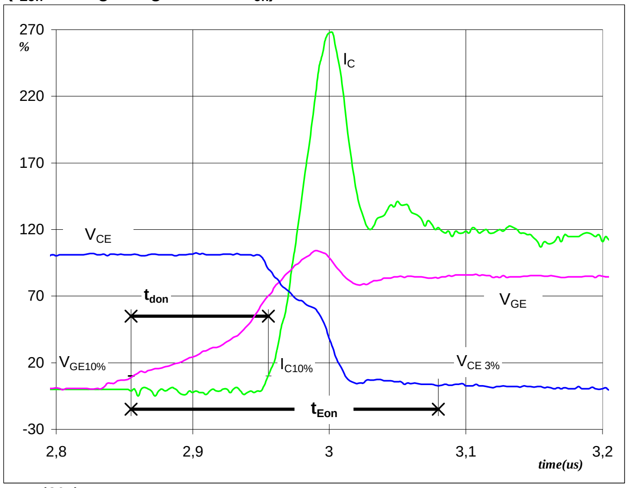
Turn-off Switching Waveforms & definition of t_{doff}, t_{Eoff}
(t_{Eoff} = integrating time for E_{off})



V_{GE} (0%) =	-15	V
V_{GE} (100%) =	15	V
V_C (100%) =	300	V
I_C (100%) =	50	A
t_{doff} =	0,17	µs
t_{Eoff} =	0,48	µs

Figure 2 Output inverter IGBT

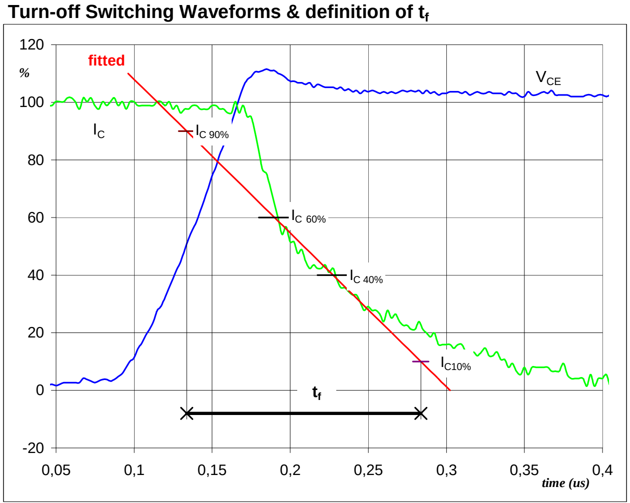
Turn-on Switching Waveforms & definition of tdon, t_{Eon}
(t_{Eon} = integrating time for E_{on})



V_{GE} (0%) =	-15	V
V_{GE} (100%) =	15	V
V_C (100%) =	300	V
I_C (100%) =	50	A
t_{don} =	0,10	µs
t_{Eon} =	0,23	µs

Figure 3 Output inverter IGBT

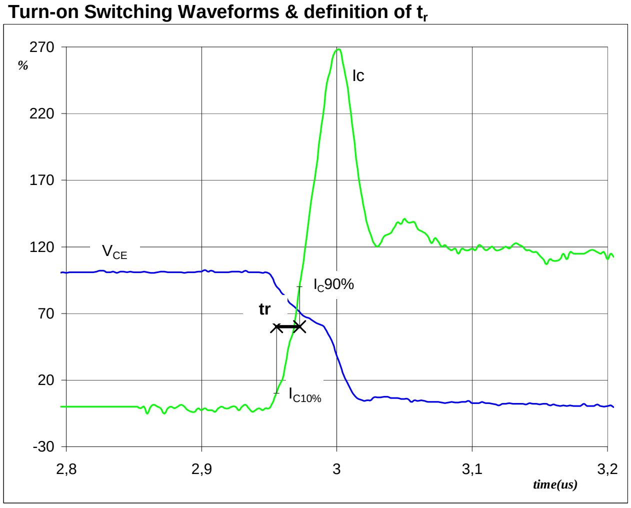
Turn-off Switching Waveforms & definition of t_f



V_C (100%) =	300	V
I_C (100%) =	50	A
t_f =	0,17	µs

Figure 4 Output inverter IGBT

Turn-on Switching Waveforms & definition of t_r

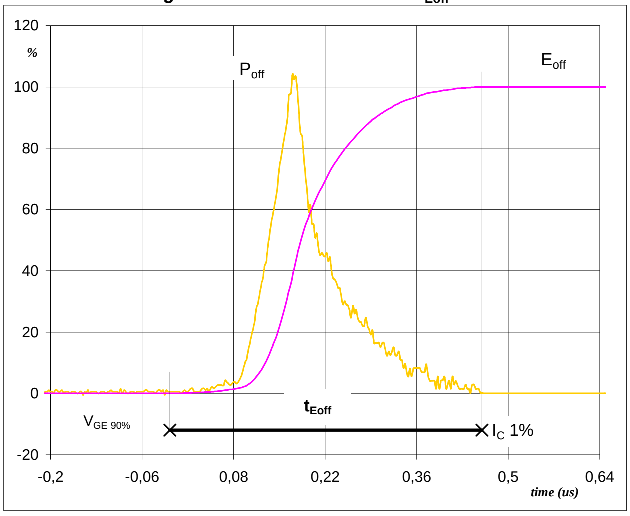


V_C (100%) =	300	V
I_C (100%) =	50	A
t_r =	0,02	µs

Switching Definitions Output Inverter

Figure 5 Output inverter IGBT

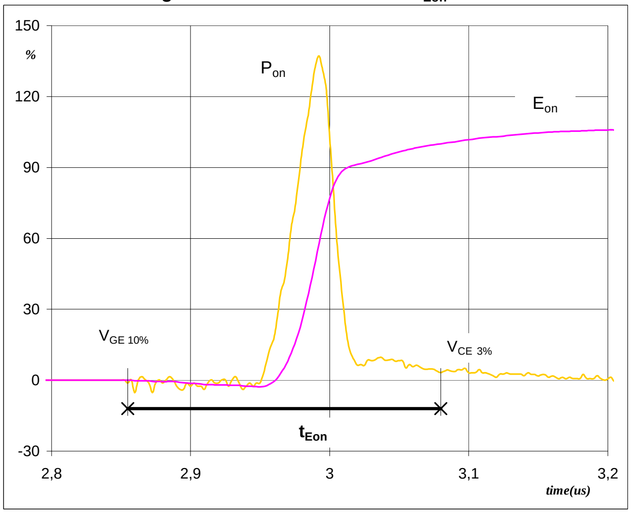
Turn-off Switching Waveforms & definition of t_{Eoff}



P_{off} (100%) =	14,94	kW
E_{off} (100%) =	1,62	mJ
t_{Eoff} =	0,48	μs

Figure 6 Output inverter IGBT

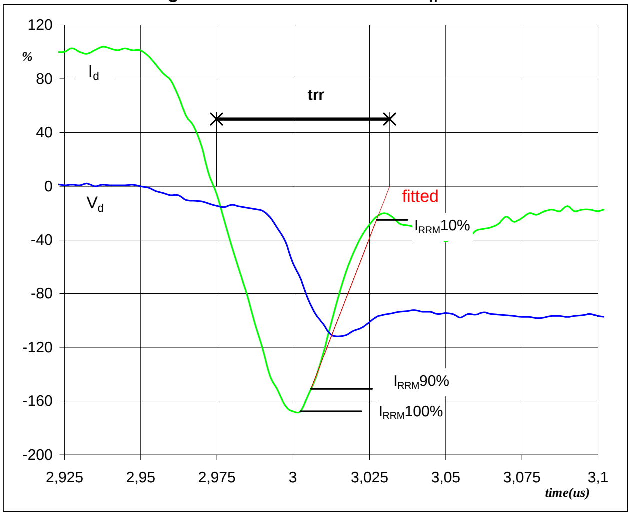
Turn-on Switching Waveforms & definition of t_{Eon}



P_{on} (100%) =	14,94	kW
E_{on} (100%) =	0,72	mJ
t_{Eon} =	0,23	μs

Figure 7 Output inverter FWD

Turn-off Switching Waveforms & definition of t_{rr}

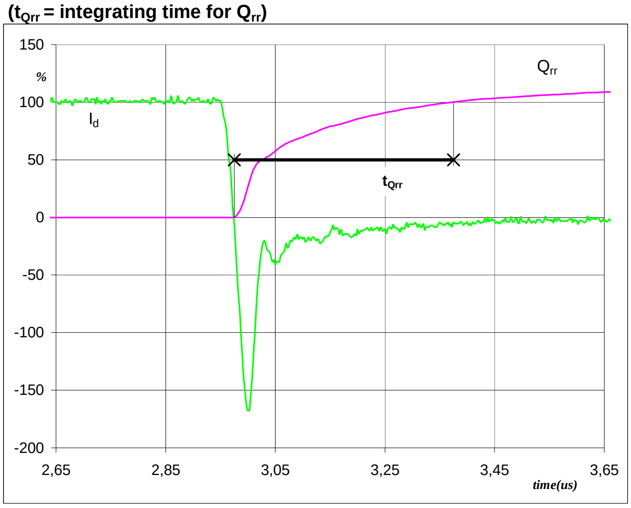


V_d (100%) =	300	V
I_d (100%) =	50	A
I_{RRM} (100%) =	84	A
t_{rr} =	0,16	μs

Switching Definitions Output Inverter

Figure 8 Output inverter FWD

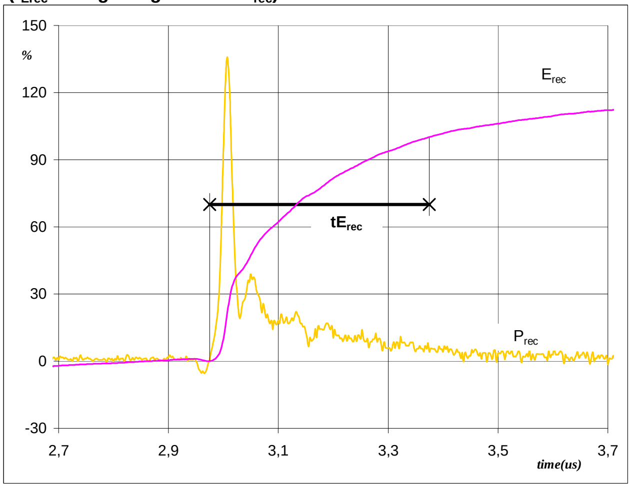
Turn-on Switching Waveforms & definition of t_{Qrr}
(t_{Qrr} = integrating time for Q_{rr})



I_d (100%) =	50	A
Q_{rr} (100%) =	4,89	μC
t_{Qrr} =	0,40	μs

Figure 9 Output inverter FWD

Turn-on Switching Waveforms & definition of t_{Erec}
(t_{Erec}= integrating time for E_{rec})



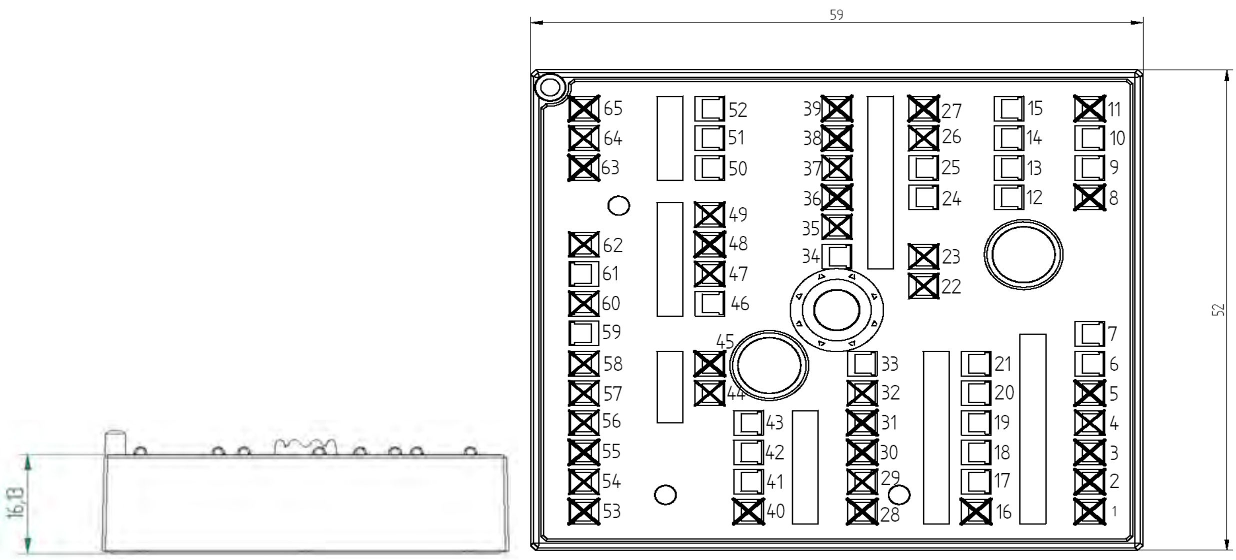
P_{rec} (100%) =	14,94	kW
E_{rec} (100%) =	1,18	mJ
t_{Erec} =	0,40	μs

Ordering Code and Marking - Outline - Pinout

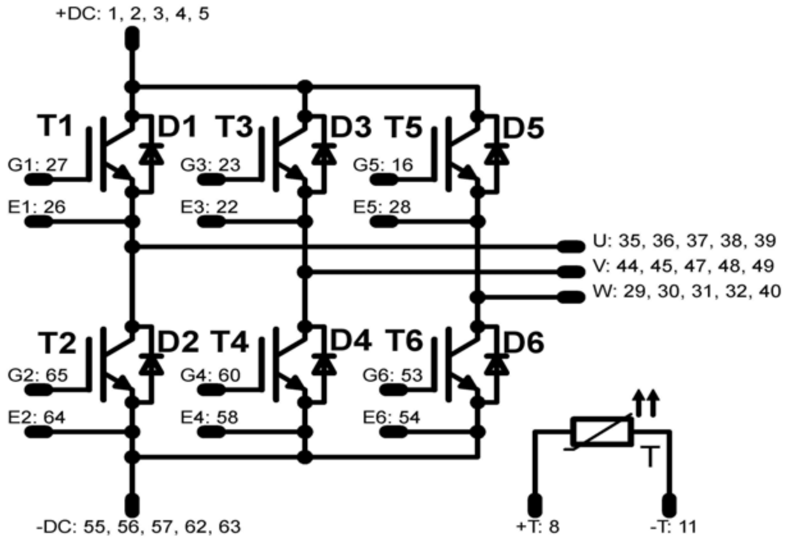
Ordering Code & Marking

Version	Ordering Code	in DataMatrix as	in packaging barcode as
with std lid (black V23990-K22-T-PM)	V23990-K232-A-/0A/-PM	K232A	K232A-/0A/
with std lid (black V23990-K22-T-PM) and P12	V23990-K232-A-/1A/-PM	K232A	K232A-/1A/
with thin lid (white V23990-K23-T-PM)	V23990-K232-A-/0B/-PM	K232A	K232A-/0B/
with thin lid (white V23990-K23-T-PM) and P12	V23990-K232-A-/1B/-PM	K232A	K232A-/1B/

Outline



Pinout



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